

EE 213, Microscopic Nanocharacterization of Materials

Class website: <https://ee213-winter16-01.courses.soe.ucsc.edu>

Time/place: Tu/Th 10-11:45am. Baskin 156

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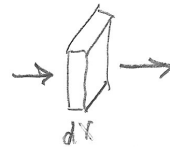
Admin. Asst. Rachel Cordero: rcordero@soe.ucsc.edu, 831-459-2921

How to Calculate Signals?

probability of interaction,

$$P = \sigma n dx$$

↑ section area ↘ # density
← thickness of material



$$\underline{P = \sigma n} \leftarrow \#/\text{area} = n dx$$

if $N = \#$ atoms in irradiated area

$J = \#$ incident particles/area/sec.

then $NJ\sigma = \#$ interactions/sec

detect some process resulting from interaction -
then $(NJ\sigma)Y$ — yield of that process

if detector has efficiency, F

then

signal detected is:

$$\underline{S = NJ\sigma Y F} \quad \#/\text{sec}$$

$$S = NJ\sigma YF$$

S = signal in counts/sec

N = # atoms in volume probed

J = current density in probe (#/area/sec)

σ = cross section for interaction (area)

Y = yield of process to be detected

F = efficiency of collection

$$N_A = S_A / J_A \sigma_A Y_A F_A$$

$$\frac{N_A}{N_B} = \frac{S_A}{S_B} \left[\frac{\sigma_B \left\{ \frac{Y_B F_B}{Y_A F_A} \right\}}{\sigma_A \left\{ \frac{Y_B F_B}{Y_A F_A} \right\}} \right] \frac{J_B}{J_A}$$

$$\frac{N_A}{N_B} = \frac{S_A}{S_B} \left[\frac{\sigma_B \left\{ \frac{Y_B F_B}{Y_A F_A} \right\}}{\sigma_A \left\{ \frac{Y_B F_B}{Y_A F_A} \right\}} \right]$$

If $J_A = J_B$

M.Isaacson, Ultramicroscopy. 49. (1993).171-178.

 K_{ab}

Microcharacterization Equation

$$S = NJ\sigma YF$$

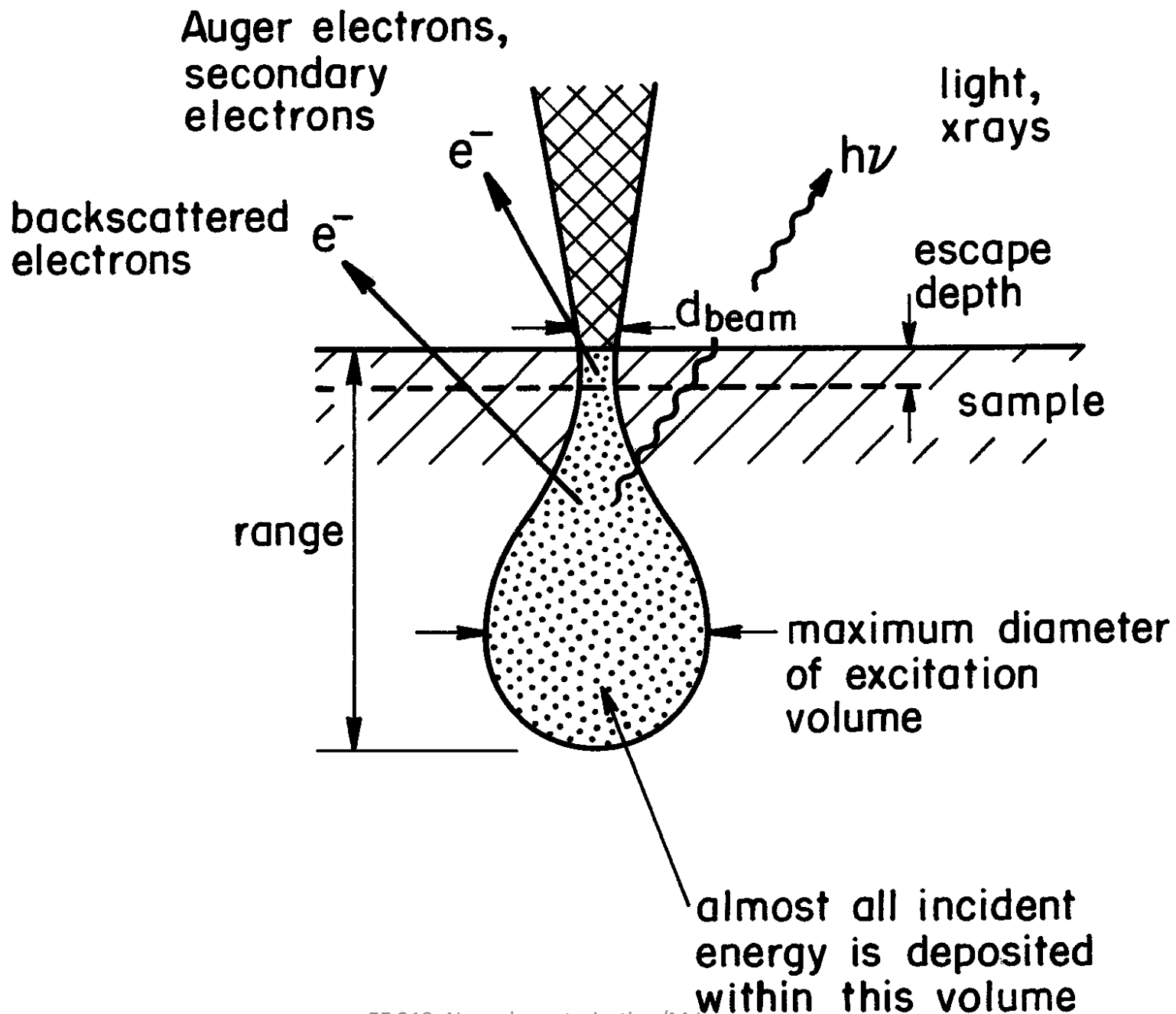
$$K_{AB} = \frac{\sigma_B}{\sigma_A} \left\{ \frac{Y_B F_B}{Y_A F_A} \right\}$$

$$\frac{N_A}{N_B} = K_{AB} \frac{S_A}{S_B}$$

Primary process

Efficiency of detection

Secondary process



sample calculations



probe
diam = d
= 10 mm
thickness
= 50 nm

$$S/N_{Al} = J \sigma Y F, \quad F = f_{emit} \cdot f_{coll} \cdot f_{DET}$$

$$J = 10^3 \text{ amp/cm}^2 \times 6 \times 10^{18} \text{ elect/sec/amp} \\ = 6 \times 10^{21} \text{ elec/sec/cm}^2$$

$$\sigma_{K}^{Al} = 2.8 \times 10^{-21} \text{ cm}^2 \text{ for } 100 \text{ keV electrons} \\ Y = \omega_K^{Al} = 2.5 \times 10^{-2}$$

assume $f_{emit} = 1$ no absorption in sample
 $f_{coll} =$ xray detector solid $\angle = d \cdot \Omega$

$$d \cdot \Omega = \frac{A}{r^2} = \frac{30 \text{ mm}^2}{(10 \text{ mm})^2} = \underline{\underline{.3 \text{ sterads}}}$$

$$\therefore f_{coll} = \frac{d \cdot \Omega}{4\pi} = 2.4 \times 10^{-2}$$

$$\therefore S/N_{Al} = \left(6 \times 10^{21} \frac{\text{elec}}{\text{sec} \cdot \text{cm}^2} \right) \left(2.8 \times 10^{-21} \text{ cm}^2 \right) \times 2.5 \times 10^{-2} \times 2.4 \times 10^{-2} \\ = 1.01 \times 10^{-2} \text{ cts/sec/atom} //$$

how many atoms?

$$V = \frac{\pi}{4} d^2 \times t \quad d=10 \text{ mm}, t=50 \text{ nm} //$$

$$V = 3.93 \times 10^6 \text{ \AA}^3$$

$$\text{density Al} \rightarrow 2.7 \text{ gm/cm}^3 \rightarrow \underline{\underline{.06 \text{ atoms/\AA}^3}}$$

$$\therefore N = 6 \times 10^{-2} \times 3.93 \times 10^6 \text{ atoms} = 2.36 \times 10^4$$

$$\therefore S = 1.01 \times 10^{-2} \times 2.36 \times 10^4 = 2.36 \times 10^3 \text{ cts/sec}$$

$$\text{if } 1\% \text{ concentration} \rightarrow \underline{\underline{S = 23.6 \text{ cts}}} *$$

5

interactions

prob, $P = \sigma n dx$

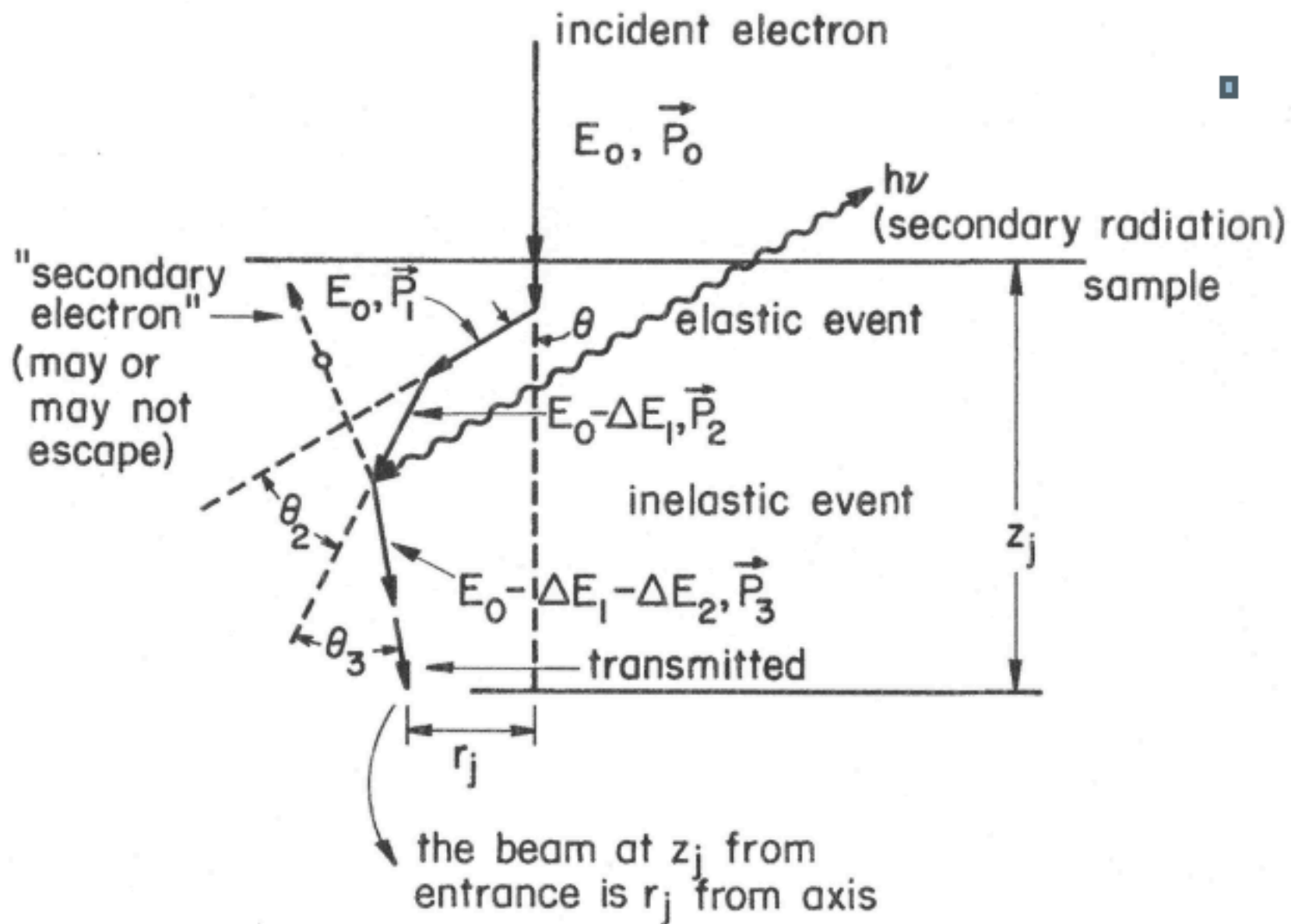
$$dJ = -JP = -J\sigma n dx$$

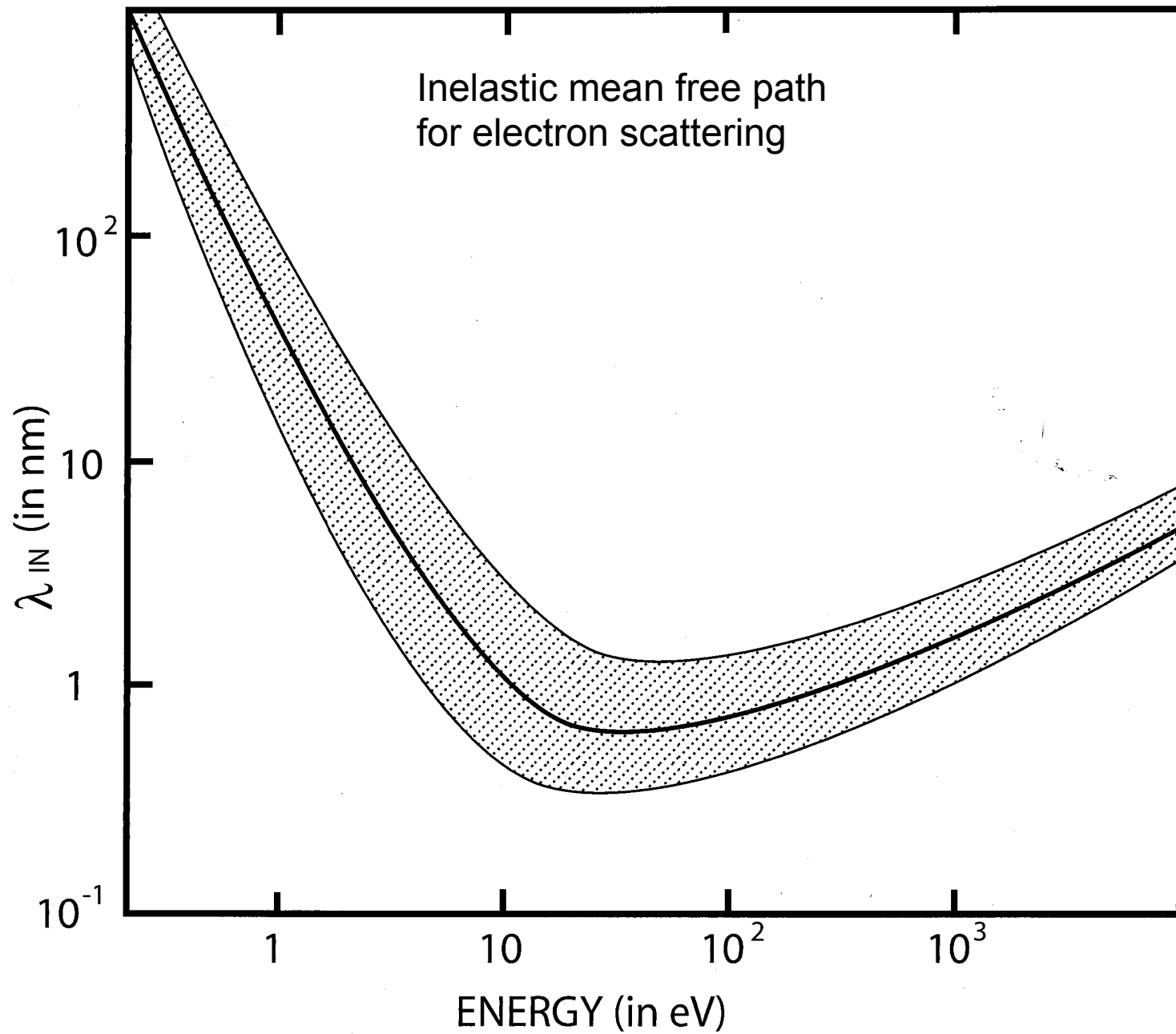
$$\int_0^x \frac{dJ}{J} = -\int_0^x \sigma n dx$$

Beer's law

$$J(x)/J(0) = e^{-\underbrace{n\sigma \cdot x}_{\Lambda = \frac{1}{n\sigma}}, \text{ mean free path}}$$

mfp = avg. dist. between interactions





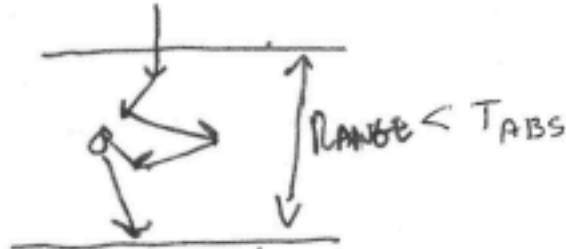
From Seah and Dench, 1979. Surf. and Interface Anal.1.36

$$\Lambda_{in} \sim 10^2 - 10^3 \text{ \AA} \text{ for } 100 \text{ keV}$$

$$\Delta E \sim 50 \text{ eV, Avg. lost/collision}$$

$$T_{ABS} \sim \frac{\Lambda_{in}}{\Delta E} \times E_0 = \frac{500 \times 10^5}{50} = 10^6 \text{ \AA}$$

Absorption length



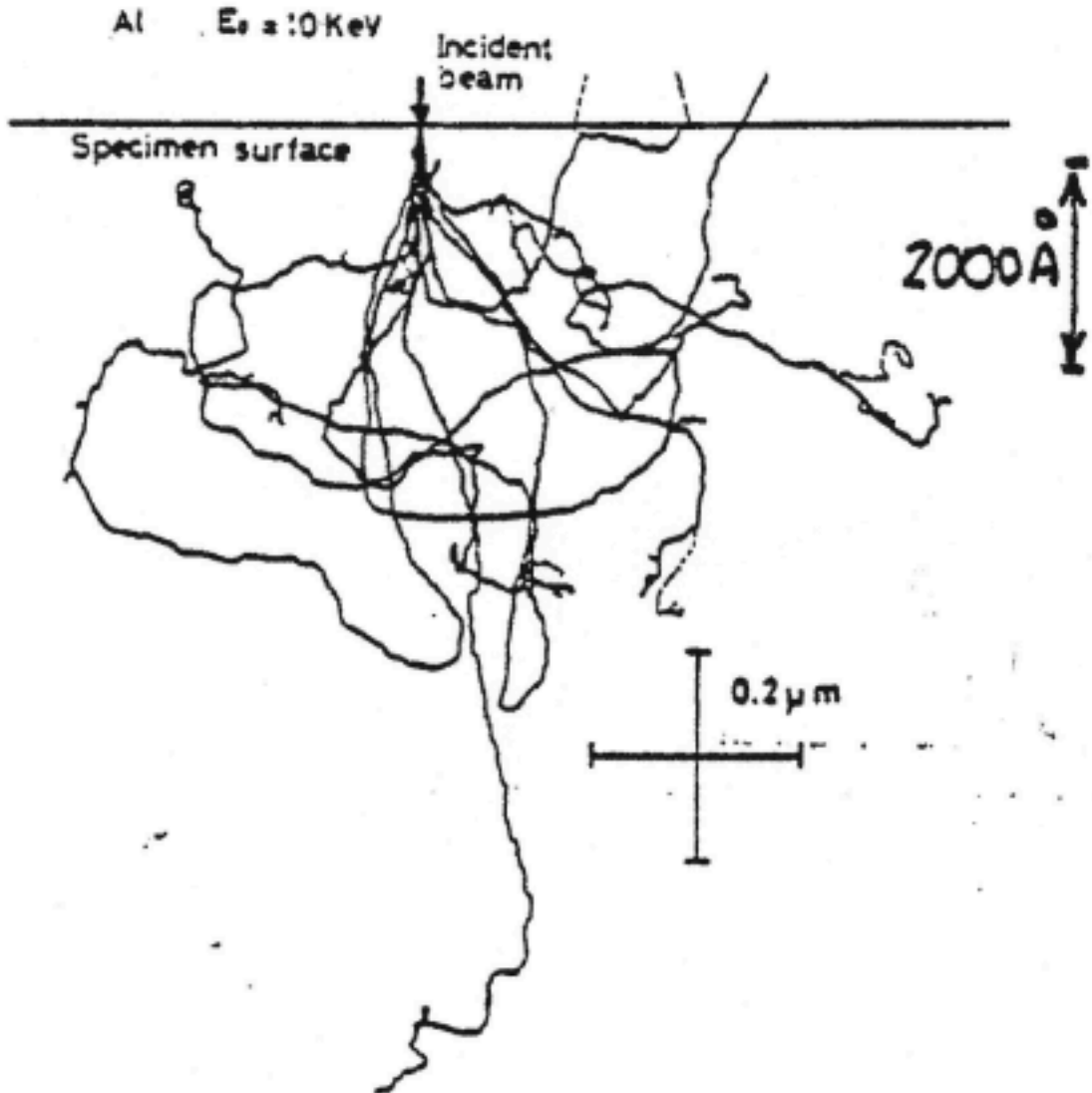
EL SCATT / 10 - 100 keV

$$\sigma_{EL} \approx \frac{39 Z^{3/2}}{E_0 \text{ meV}} \text{ \AA}^2$$

$$\Lambda_{EL} = \frac{1}{n \sigma_{EL}} \rightarrow \text{Si} \rightarrow \Lambda_{EL} \approx 5700 \text{ \AA}$$

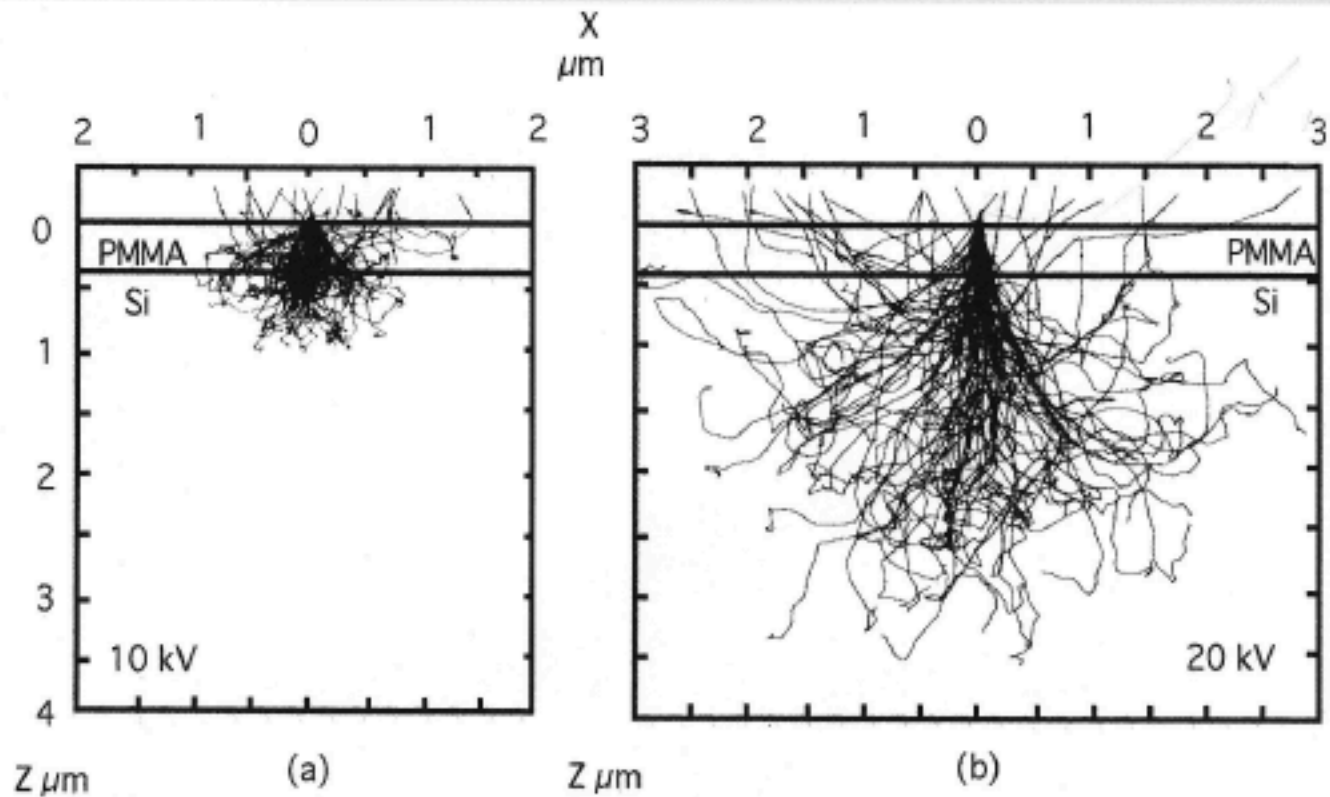
$$\text{Au} \rightarrow \Lambda_{EL} \approx 30 \text{ \AA}$$

Monte Carlo Simulation: 10KeV electron scattering in Al



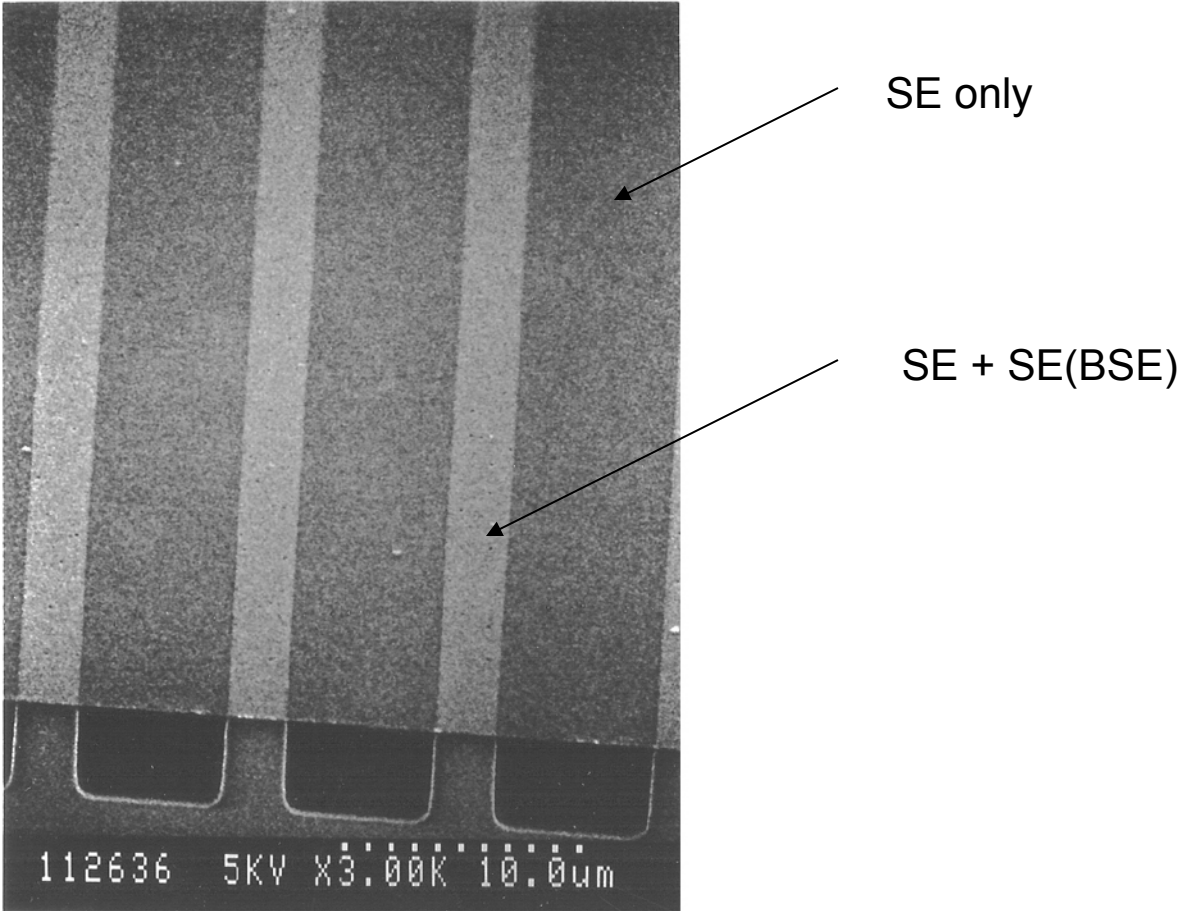
From D.Kyser

Electron beam interactions



- forward scattering
- backscattering
- secondary electrons
- other secondary "particles"

100 nm Aluminum Film Self-Supported on Silicon Fingers
secondary electron image



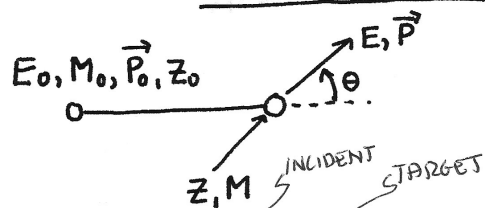
M. Isaacson and K. Lin

Elastic scattering

(7)

Rutherford Scattering (Coulomb scatt)

Phil. Mag. 21. 669 (1911)



$$\frac{d\sigma}{d\Omega} \propto \frac{(ez_0)^2 (ez)^2}{E_0^2} \left[\frac{4(\cos\theta + \sqrt{1-x^2\sin^2\theta})^2}{\sin^4\theta \sqrt{1-x^2\sin^2\theta}} \right]^2$$

where $x = M_0/M$ same for RBS NOTE at $\theta=0$

for electrons $x \ll 1$ and $z_0=1$

$$\therefore \frac{d\sigma}{d\Omega} \propto \frac{e^4 z^2}{E_0^2} \frac{1}{\sin^4(\theta/2)}$$

OK for larger θ

for electrons / Ruth Scatt \sim elastic

ie, virtually no energy loss — (but some)

$$\Delta E_{\text{MAX}} \cong \frac{4m_e}{M} E_0$$

max. energy that can be transferred in collision

$$\frac{m_e}{m_p} = 5.46 \times 10^{-4}$$

eg, 100keV electrons
iron, $A=55.8$ amu

$$\therefore \Delta E_{\text{MAX}} \cong 3.9 \text{ eV}$$

correction to "Rutherford" Scattering

when incident e^- comes close to nucleus
Ruth. scattering \Rightarrow probability $\propto Z^2$

BUT, if e^- not so close,

nuclear charge, Z , is shielded
by atomic electrons,

so inc. e^- doesn't see full + charge Z ,
but only an effective $Z_{\text{EFF}} < Z$

This means potential is not $V(r) \propto \frac{Ze-e}{r^2}$ (Coulomb)

but rather, $V(r) \propto \frac{Z_{\text{EFF}} e^2}{r^2}$

$Z_{\text{EFF}} \cong Ze^{-r/a}$ where a is a "screening" radius

(ie, further away the elec. is, the less the
"effective" nuclear charge is for "scattering")

Different atomic models take this into account.
analytic ones are approx. but easy to use.

1930's Lenz-Wentzel / $a = a_0 Z^{-1/3}$

\rightarrow Bohr radius
 $= .529 \text{ \AA} (H)$

1970's Langmuir et al / more accurate
 $a = 0.9 a_0 Z^{-1/4}$

\rightarrow reference

both show $a \downarrow$ as $Z \uparrow$

corrections to Rutherford Scattering (2)

the $\frac{1}{r}$ potential (Coulomb) gave a scatt. x section

$$\frac{d\sigma}{d\Omega} \propto \frac{1}{[\sin^2(\frac{\theta}{2})]^2} \rightarrow \frac{1}{[\theta^2]^2} \text{ small } \theta$$

a screened potential, $\frac{1}{r} e^{-r/a}$ gives (for small θ)

$$\frac{d\sigma}{d\Omega} \rightarrow \frac{1}{[\theta^2 + \theta_0^2]^2}$$

$$\text{where } \theta_0 = \frac{\lambda}{2\pi a}$$

$\lambda = \frac{h}{p}$ ← Planck's const. momentum of inc. e^-
 λ ← wavelength of inc. e^-

example: take Al $\Rightarrow Z=13$

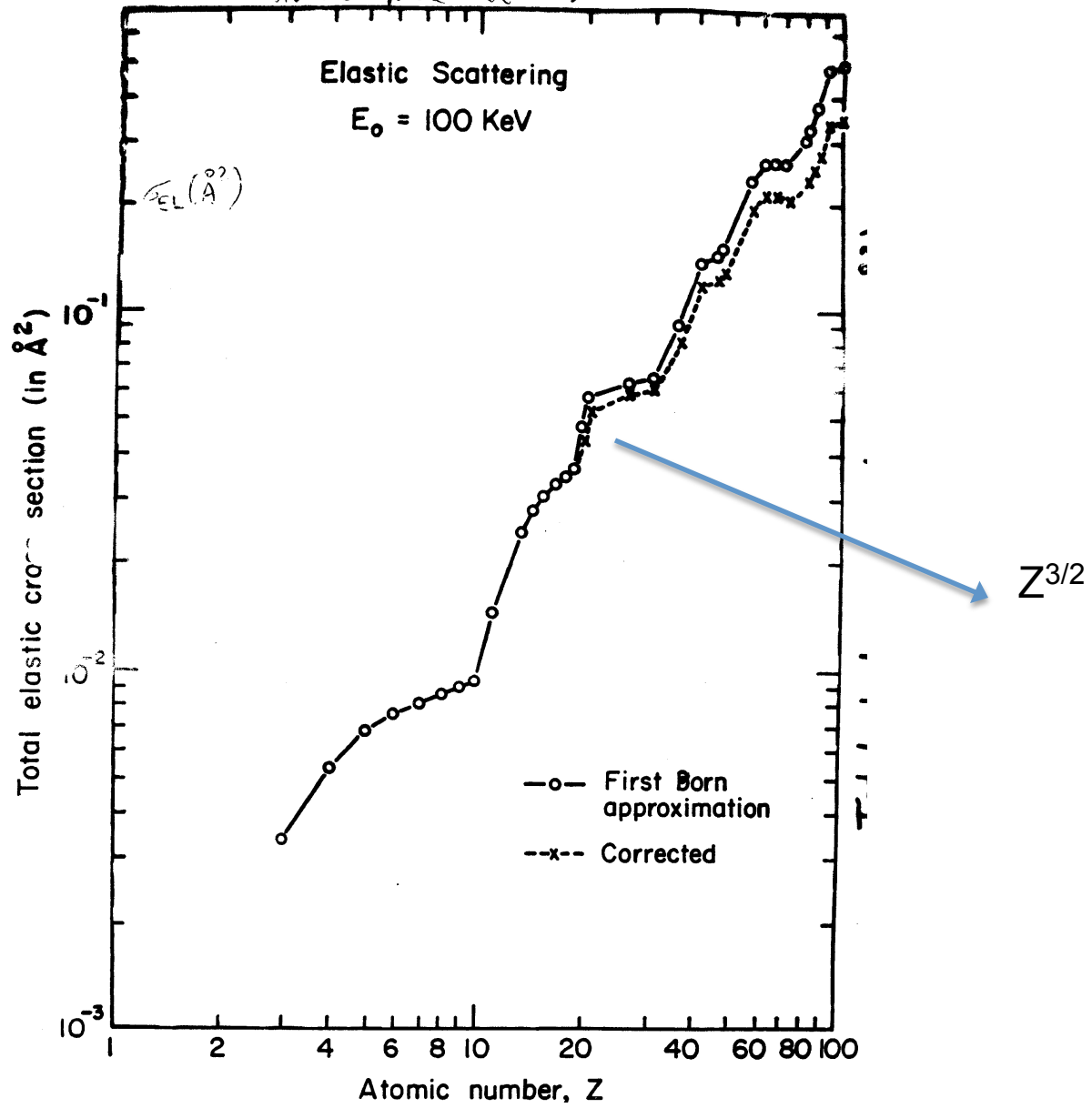
$$a = 0.9 a_0 Z^{-1/4}, \quad a_0 = 0.529 \text{ \AA} \text{ Bohr radius}$$

$$\therefore a = 0.91 \text{ \AA}$$

$$\theta_0 = \frac{\lambda}{2\pi a}, \quad \lambda_{100\text{keV}} = 0.039 \text{ \AA}$$

$$\therefore \boxed{\theta_0 = 69 \text{ m}\Gamma}$$

~ 2 orders of magnitude (or more) greater than inelastic char. scatt. $\neq \theta_E$



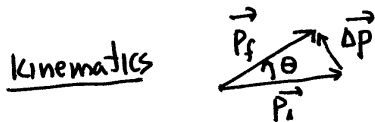
inelastic scattering

elec \rightarrow elec / Z electrons in atom

$$\therefore \frac{d\sigma}{d\Omega} \rightarrow \sum_{i=1}^Z \frac{(e^2)(e^2)}{\text{same stuff}} \rightarrow \frac{e^4 Z}{\text{stuff}}$$

when you go through details
not quite free electrons -

wind up with $\frac{d^2\sigma}{dE d\Omega} \propto \frac{1}{(\Delta p)^2}$



$$\Delta p = \hbar q = [P_f^2 + P_i^2 - 2P_i P_f \cos\theta]^{1/2}$$

for small energy loss, $\Delta E \ll E_{inc}$
and small angles ($< 20^\circ$)

we get $\Delta E \approx \frac{P_i}{m} (P_i - P_f)$

min. momentum transferred ($\theta=0$)

$$\Delta p_{min} = P_i - P_f \approx \frac{m \Delta E}{P_i} = \frac{\Delta E}{v_i}$$

so for small θ , we write

$$\Delta p \approx \left[\underbrace{(P_i - P_f)^2}_{\Delta E / v_i} + P_i P_f \theta^2 \right]^{1/2} = P_i \left[\left(\frac{\Delta E}{P_i v_i} \right)^2 + \theta^2 \right]^{1/2}$$

$P_i \sim P_f$

$\theta_E = \frac{\Delta E}{P v}$ characteristic inelastic scatter

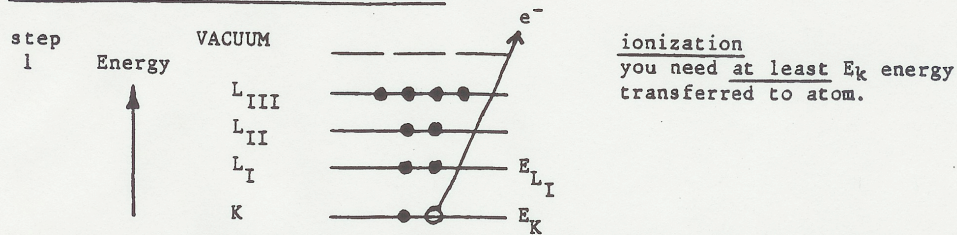
take $\Delta E = 50 \text{ eV}$
 $E = 100 \text{ keV}$

$$\theta_E \approx \frac{\Delta E}{2E} = \frac{1}{4} \text{ mrad}$$

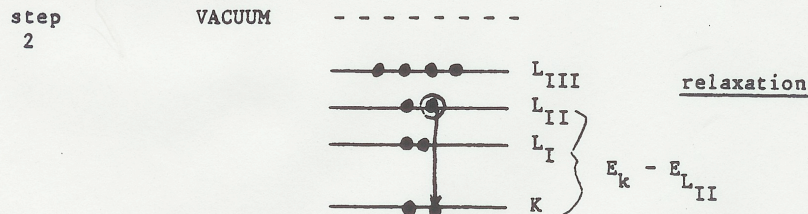
$$\therefore \frac{d\sigma}{d\Omega} \rightarrow \frac{1}{\theta^2 + \theta_E^2}$$

MITIO INOKUTI
Rev. Mod. Phys. 43, 297 (1971)

Ionization, Excitation and Emission

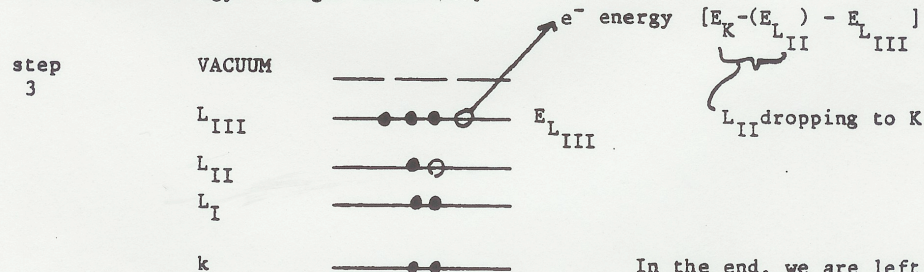


With a hole in the inner shell the atom is energetically unstable. Relaxation occurs by a more outer shell electron filling the hole; e.g., an L_{II} electron depicted below

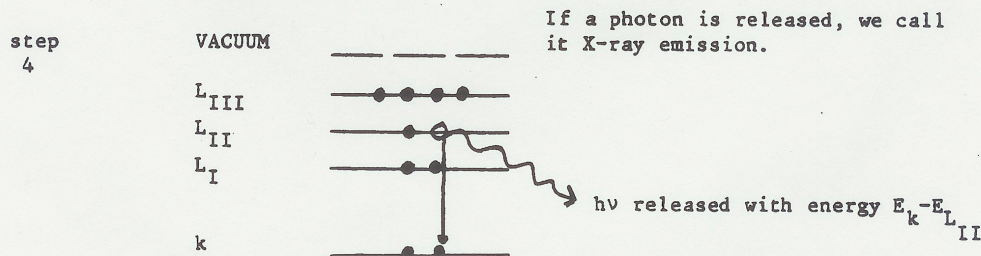


In this step $E_k - E_{L_{II}}$ energy is released. This can be given up either by

releasing a photon (X-ray emission) or given to another electron (either in the same level or one with lower binding energy). If the 2nd electron has sufficient excess kinetic energy it will be ejected into the vacuum where we can measure its energy. [Auger emission.]



In the end, we are left with a doubly ionized atom. This is called Auger emission.



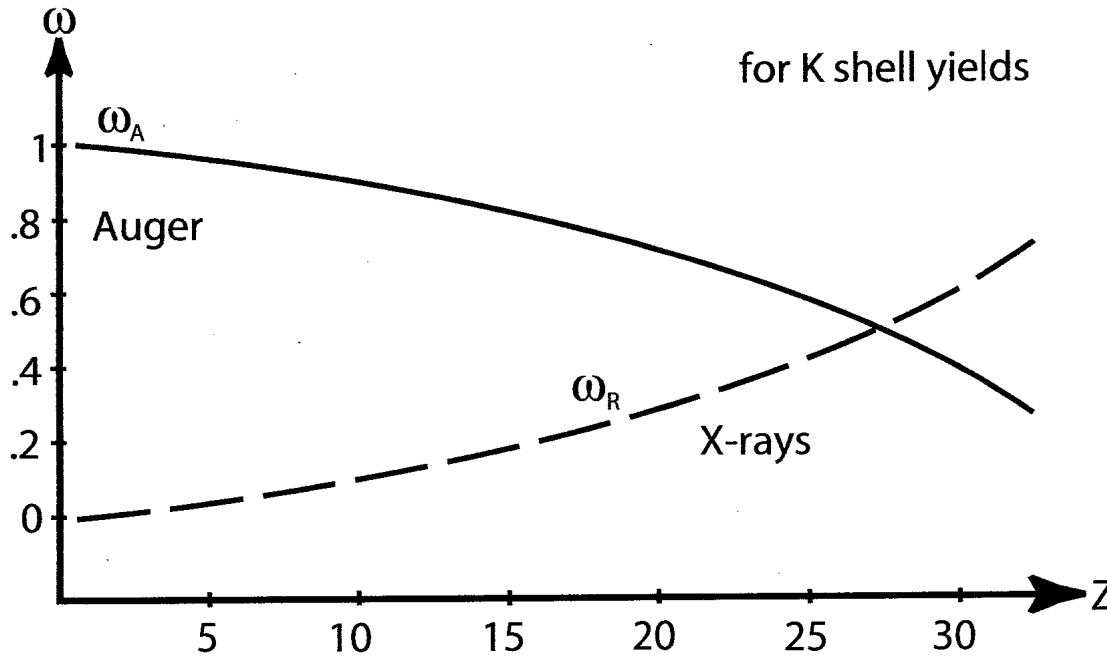
Xray and Auger Electron Yields

$$\omega \approx \frac{Z^4}{Z^4 + b}, \quad b = \begin{cases} 1.12 \times 10^6 & \text{K shell} \\ 6.4 \times 10^7 & \text{L}_3 \text{ shell} \end{cases}$$

Burhop,
Auger Effect
CUP 1952

Cambridge University Press

$$\omega_{\text{X-RAYS}} \approx 1 - \omega_{\text{AUGER}}$$



2. ELECTRON BINDING ENERGIES FOR AES

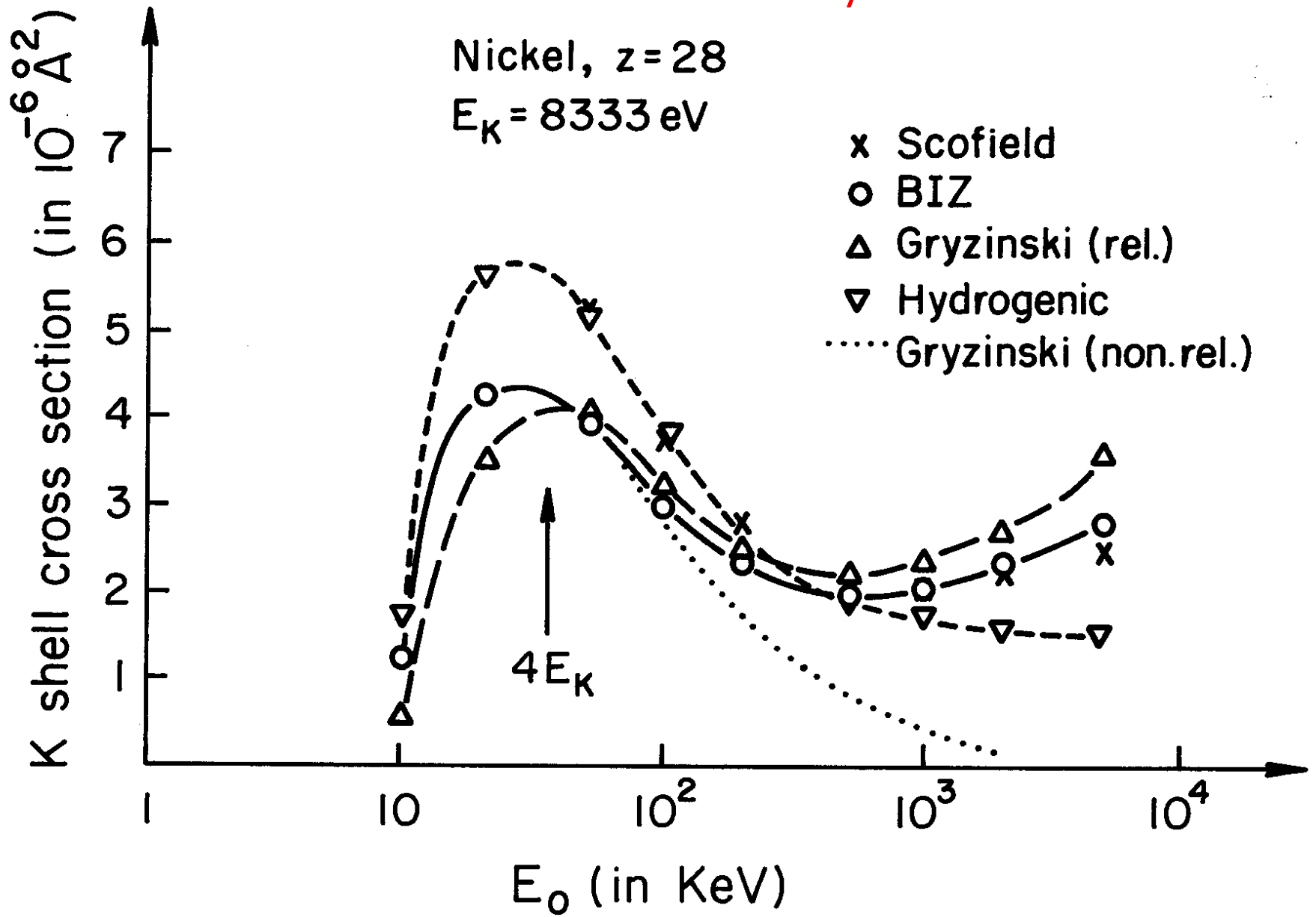
(eV)

	1s _X	2s _X	2p _X	2p _X	3s _X	3p _X	3p _X	3d _X	3d _X	4s _X	4p _X	4p _X	4d _X	4d _X	4f _X	4f _X	5s _X	5p _X	5p _X	5d _X	5d _X	
	K	L _I	L _{II}	L _{III}	M _I	M _{II}	M _{III}	M _{IV}	M _V	N _I	N _{II}	N _{III}	N _{IV}	N _V	N _{VI}	O _I	O _{II}	O _{III}	O _{IV}	O _V	O _{VI}	
1H	14																					
2He	25																					
3Li	55																					
4Be	111																					
5B	188			5																		
6C	284			7																		
7N	399			9																		
8O	532	24		7																		
9F	686	31		9																		
10Ne	867	45		18																		
11Na	1 072	63		31		1																
12Mg	1 305	89		52		2																
13Al	1 560	118	74		73	1																
14Si	1 839	149	100		99	8	3															
15P	2 149	189	136		135	16	10															
16S	2 472	229	165		164	16	8															
17Cl	2 823	270	202		200	18	7															
18Ar	3 203	320	247		245	25	12															
19K	3 608	377	297		294	34	18															
20Ca	4 038	438	350		347	44	26	5														
21Sc	4 493	500	407		402	54	32	7														
22Ti	4 965	564	461		455	59	34	5														
23V	5 465	628	520		513	66	38	2														
24Cr	5 989	695	584		575	74	43	2														
25Mn	6 539	769	652		641	84	49	4														
26Fe	7 114	846	723		710	95	56	6														
27Co	7 769	926	794		779	101	60	3														
28Ni	8 333	1 008	872		855	112	68	4														
29Cu	8 979	1 096	951		931	120	74	2														
30Zn	9 659	1 194	1 044		1 021	137	87	9														
31Ga	10 367	1 298	1 143		1 116	158	107	18														
32Ge	11 104	1 413	1 249		1 217	181	129	29														
33As	11 867	1 527	1 359		1 323	204	147	41														
34Se	12 658	1 654	1 476		1 436	232	168	57														
35Br	13 474	1 782	1 596		1 550	257	189	69														
36Kr	14 326	1 921	1 727		1 675	289	223	89														
37Rb	15 200	2 065	1 864		1 805	322	248	111														
38Sr	16 105	2 216	2 007		1 940	358	280	133														
39Y	17 039	2 373	2 155		2 080	395	313	158														
40Zr	17 998	2 532	2 307		2 223	431	345	180														
41Nb	18 986	2 698	2 465		2 371	469	379	205														
42Mo	20 000	2 866	2 625		2 520	505	410	227														
43Tc	21 044	3 042	2 793		2 677	544	445	253														
44Ru	22 117	3 224	2 967		2 838	585	483	279														
45Rh	23 220	3 412	3 146		3 004	627	521	307														

	6s _X	6p _X	6p _X	6d _X	6d _X
	P _I	P _{II}	P _{III}	P _{IV}	P _V
82Pb	3		1		
83Bi	8		3		
84Po	12		5		
85At	18		8		
86Rn	26		11		
87Fr	34		15		
88Ra	44		19		
90Th	60	49	43	2	2

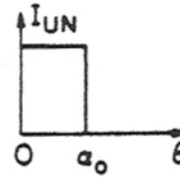
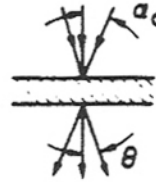
Siegnahn, et.al. ESCA. 1967

Calculations of K shell excitation by electrons

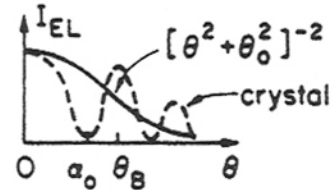
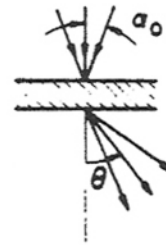


SCATTERING MECHANISMS FOR CHARACTERIZATION

1. UNSCATTERED
 $\Delta E = 0, \Delta P = 0$



2. ELASTICALLY
 SCATTERED
 $\Delta E \approx 0$
 $\sigma_{EL} \sim Z^{3/2}$
 $\theta_0 \sim \lambda / 2\pi a \approx \theta_B$

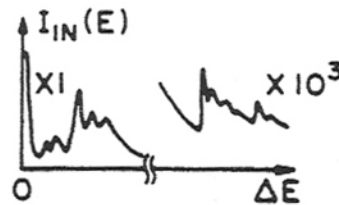
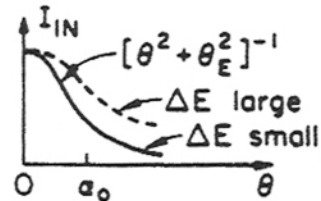
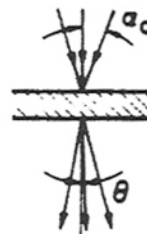


3. INELASTICALLY
 SCATTERED

$$\theta_E \approx \frac{\Delta E}{P_0 V_0}$$

$$\sigma_{IN} \sim Z^{1/2}$$

$$\frac{d\sigma_{IN}}{dE} \text{ material specific}$$



Negative Staining in the Transmission Electron Microscope

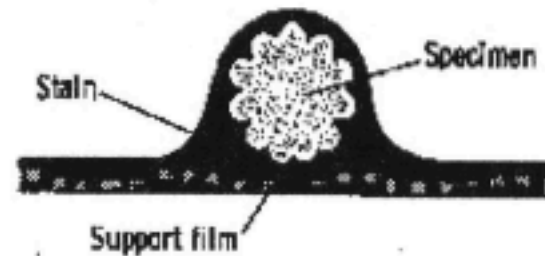
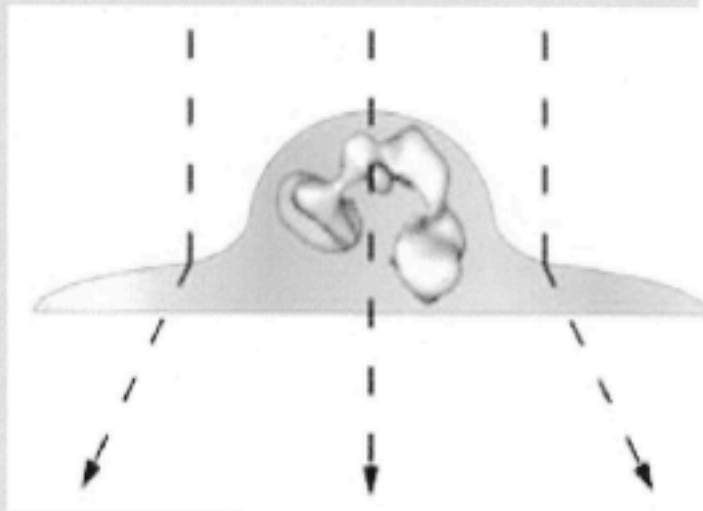
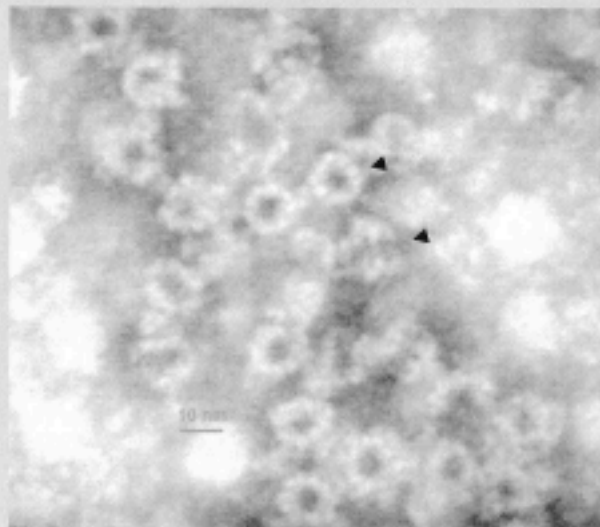


Fig. II.39. Schematic representation of a specimen particle completely embedded in a negative stain. (From Hayat and Miller, p.2)

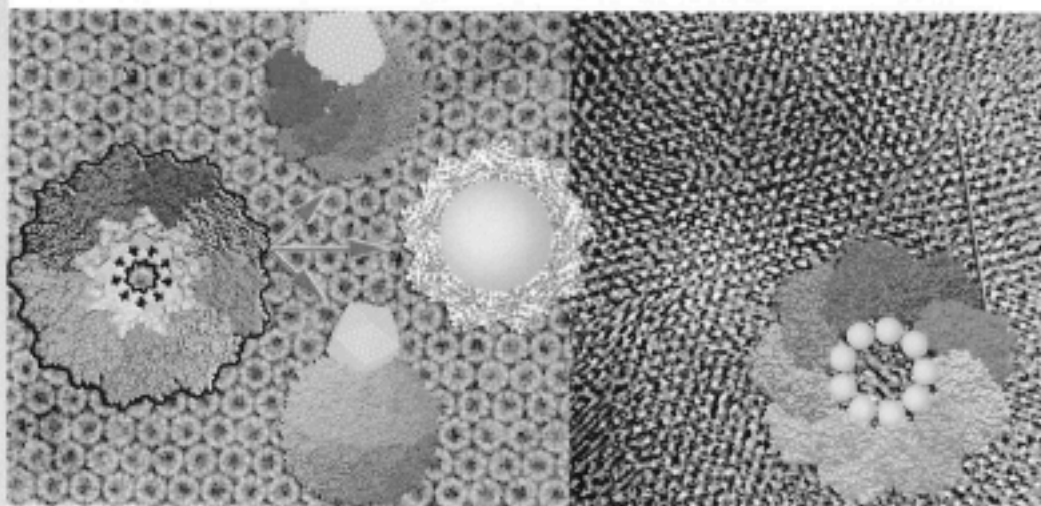
Lipid imprinting and Self-Assembly Protein Arrays



Top view

Side view

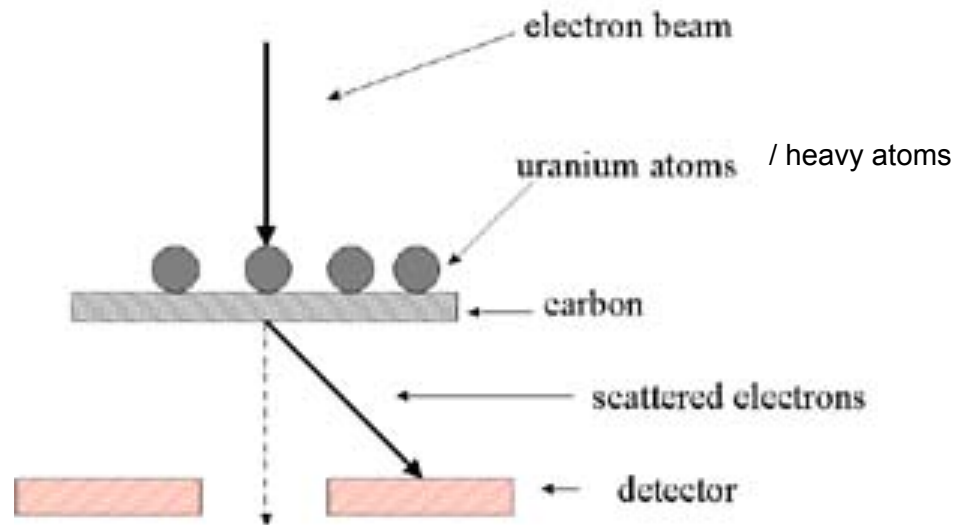
STEM image



TEM image

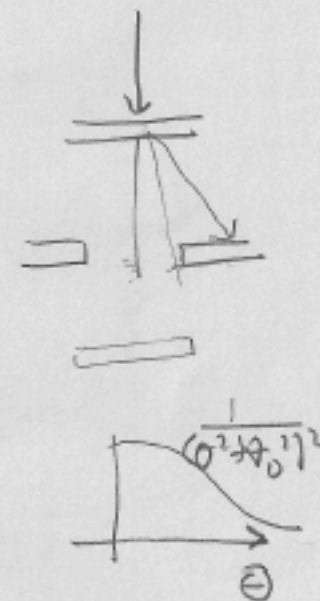
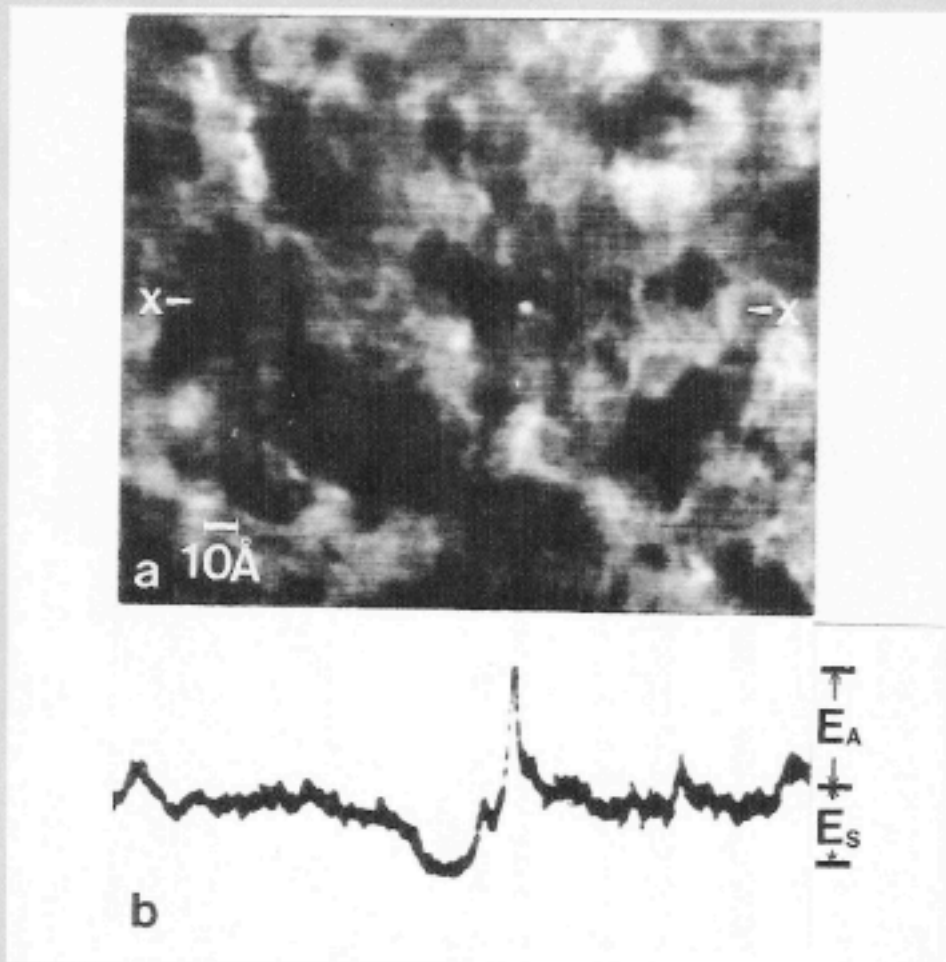
Trent, Macmillan,
Pavaia, Isaacson

Nanodevices Require Atomic Characterization



Scanning Transmission Electron Microscope

ADF Signal of Individual High Z Atom on Thin Carbon Substrate, Energy = 40keV



M.Isaacson, M.Ohtsuki and M.Utlaut (1979)

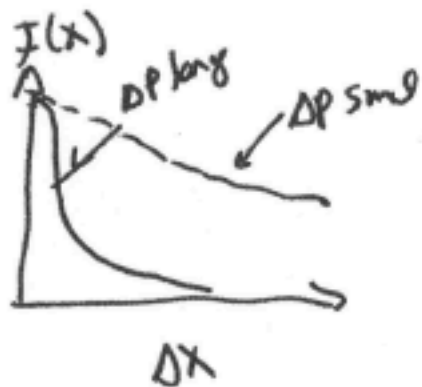
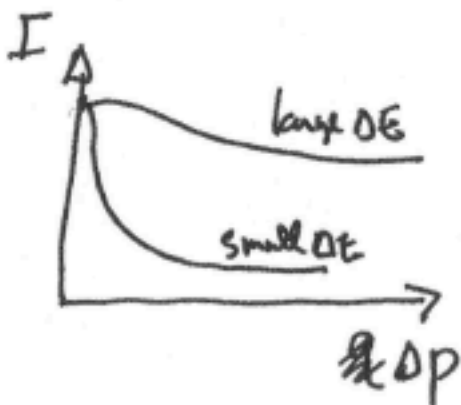
$$\Delta p \Delta x \sim h$$

$$\Delta x \sim \frac{h}{\Delta p}$$

$$\Delta x \approx \frac{2\pi}{q}$$

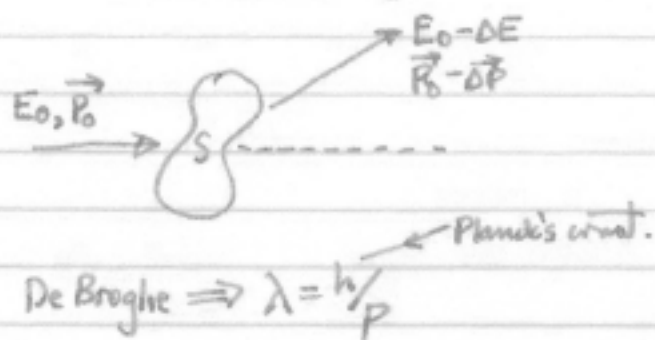
Impact
parameters

$$\Theta_{AE} = \frac{\Delta E}{pN} = \frac{m \Delta E}{p^2} \rightarrow \frac{\Delta E}{2E} \quad \text{non-rel.}$$



$$\frac{d\sigma}{dE} \propto -\text{Im} \frac{1}{\epsilon(E)}$$

Electron Scattering



$$\text{De Broglie} \Rightarrow \lambda = h/p$$

λ related to "interaction" distance

$\Delta p \Delta x \sim h$, uncertainty principle

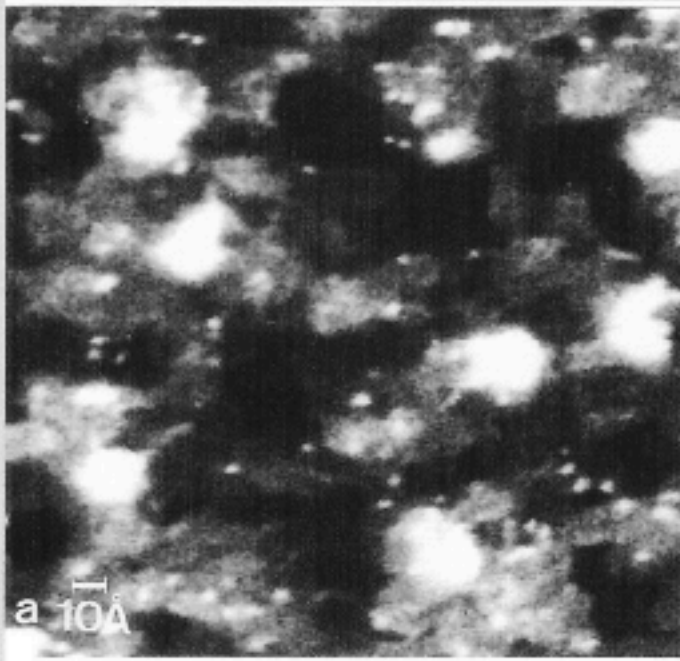
\therefore we define an inverse length (or inverse impact parameter), q

$$\Delta p = \frac{h}{2\pi} q = \hbar q$$

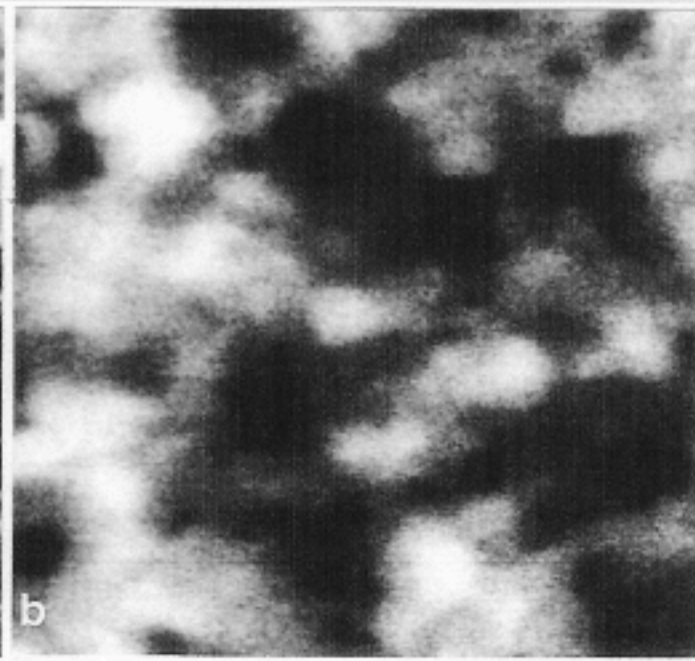
if Δp is small then q is small $\Rightarrow \Delta x$ is large
- these generally are "inelastic collisions"
($e^- \rightarrow e^-$)

if Δp is large then q is large $\Rightarrow \Delta x$ is small
- these generally are collisions with the "nucleus"
"elastic" collisions

Demonstration of the Non-Localization of Inelastic Electron Scattering
(a manifestation of the Heisenberg Uncertainty Principle)



Elastic Scattering

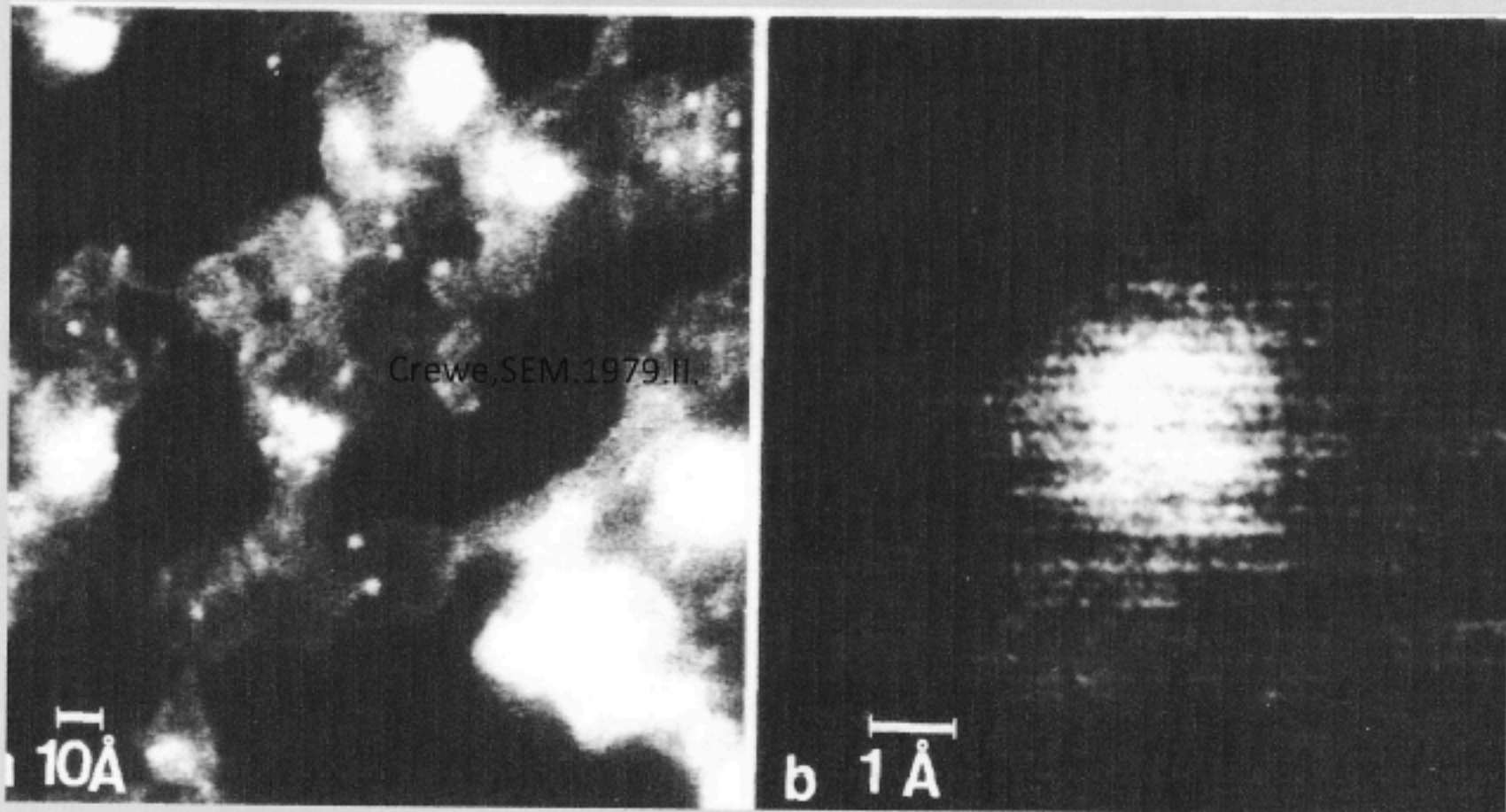


Inelastic Scattering

Pt on Thin Carbon Substrate

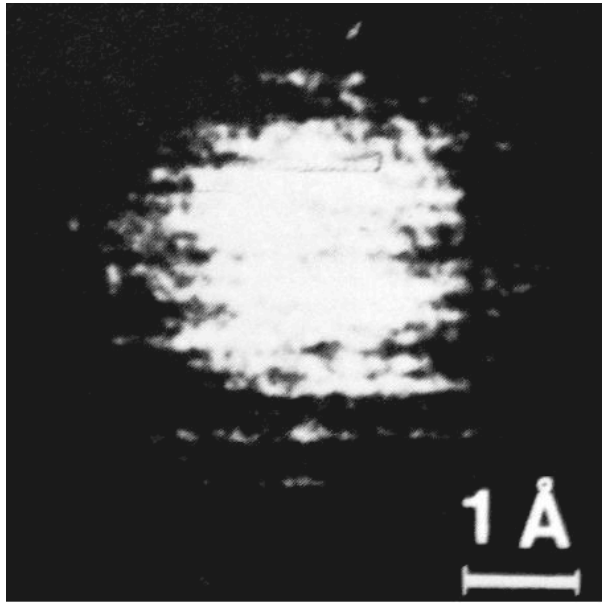
Isaacson, Utlaut and Kopf, 1980 (in Springer Topics in Current Physics, Vol. 13, Chapter 7)

Au atoms deposited on 1 nm thick carbon substrate
Annular dark Field Signal, Beam Energy = 40keV

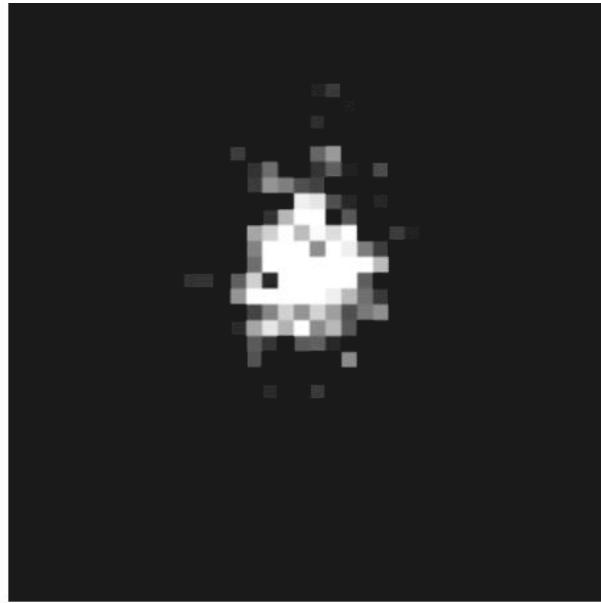


M. Ohtsuki, M.S. Isaacson and A.V. Crewe. SEM79.II.375-382 (SEM Inc.)

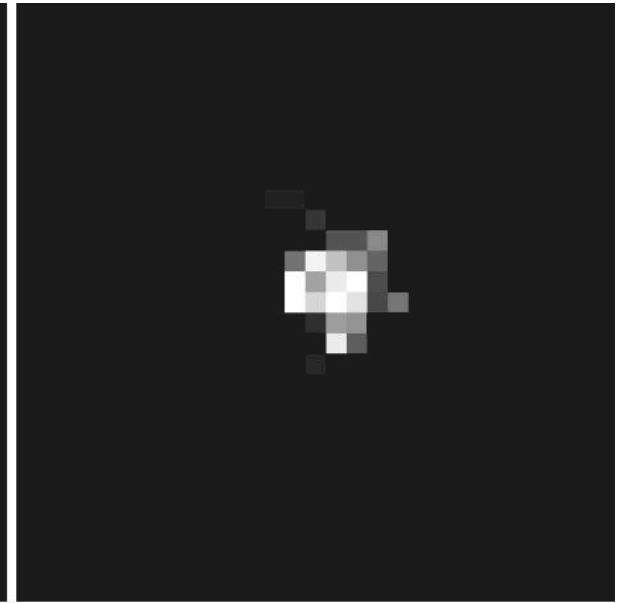
Single atom imaging by annular dark field (ADF) STEM



Chicago STEM ~1975
40 keV: 2.5 Å Au atom



Nion UltraSTEM 2007
100 keV: 1 Å Au atom



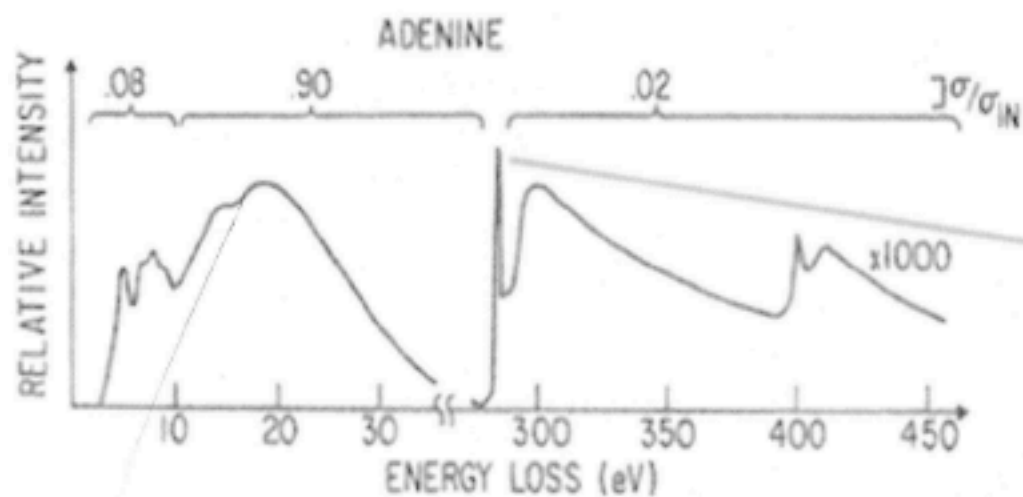
Nion UltraSTEM 2010
200 keV: 0.6 Å Au atom

The resolution has improved, and so has the stability.

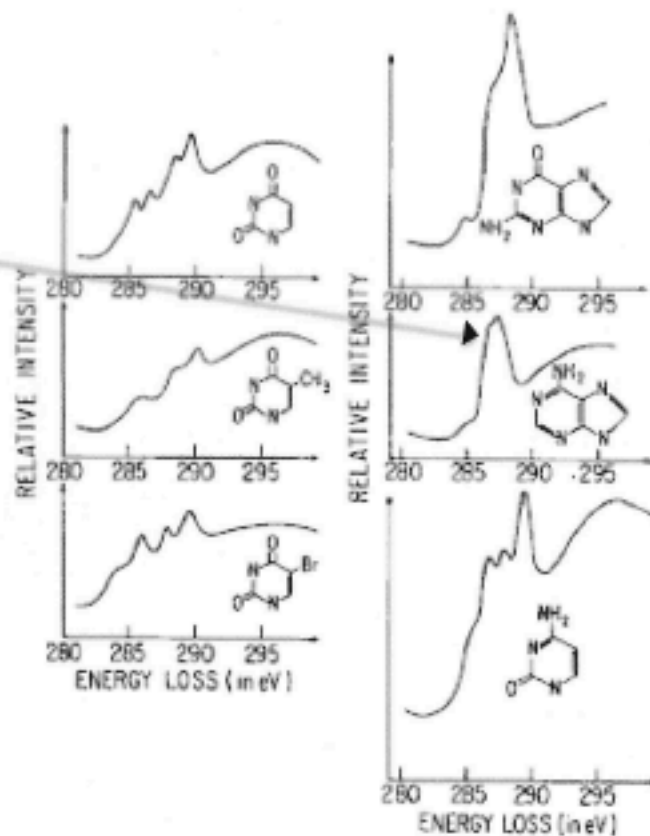
In ADF STEM, the potential well around the nucleus is imaged. ADF STEM can thus potentially show atoms as only about 0.3 Å large.

From Ondrej Krivanek

EELS of Nucleic Acid Bases obtained Using 25keV Incident Electrons



M. Isaacson, D. Johnson and A.V. Crewe, *Rad. Res.* 55 (1973). 205.



M. Isaacson and D. Johnson,
Ultramicroscopy. 1 (1975). 33-52.

EELS from nucleic acid bases

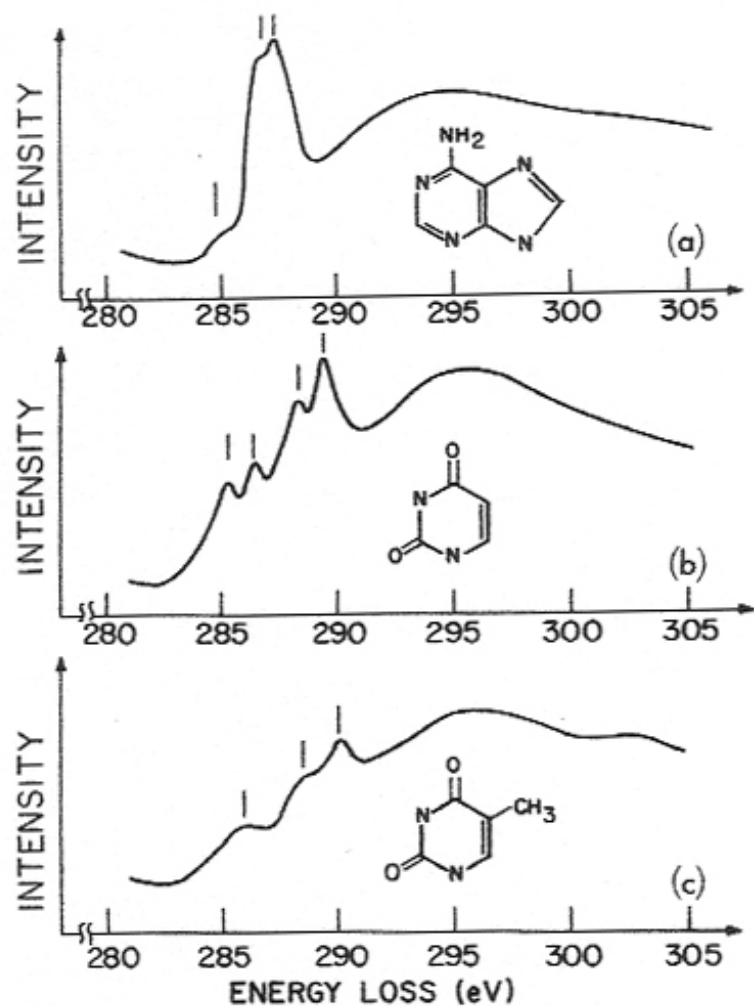


FIG. 2. Characteristic electron energy loss spectra of adenine, $C_5N_5H_5$ (a), uracil, $C_4N_2O_2H_4$ (b), and thymine, $C_5N_2O_2H_6$ (c) showing the fine structure in the region of the carbon K -shell excitation edge. The peripheral hydrogen atoms in the chemical structural formulas have been omitted for clarity.

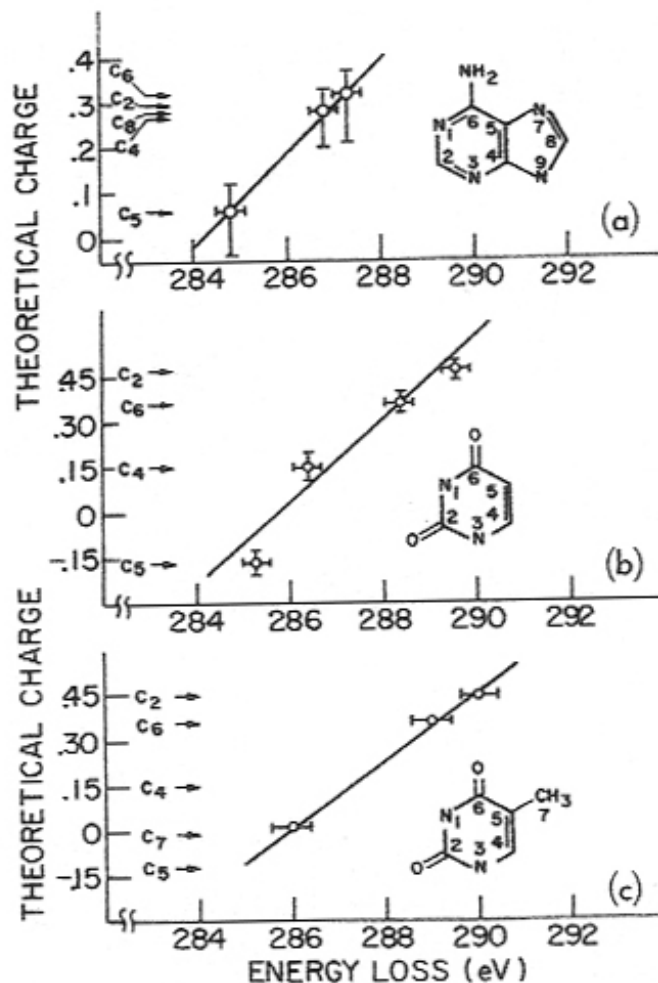
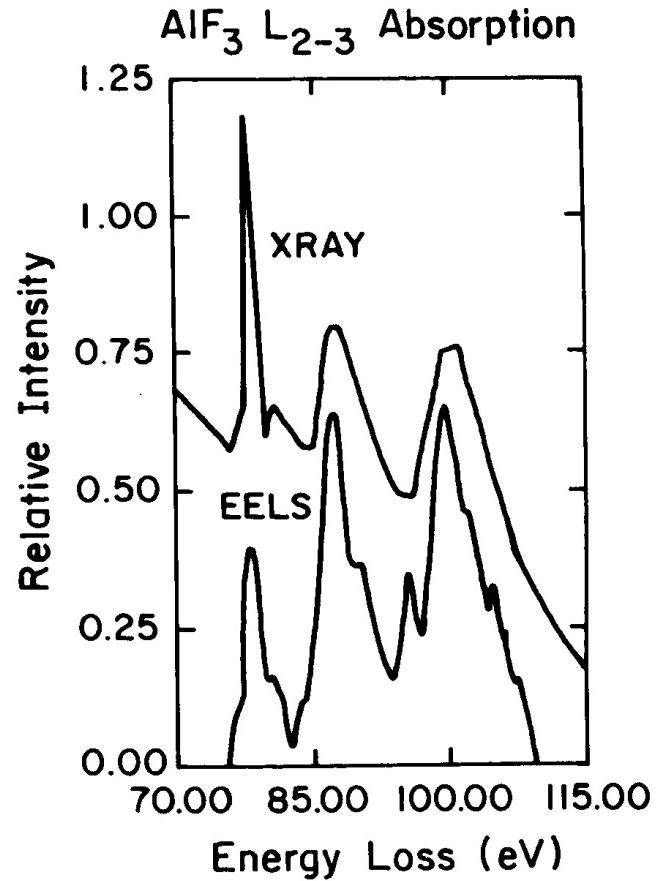
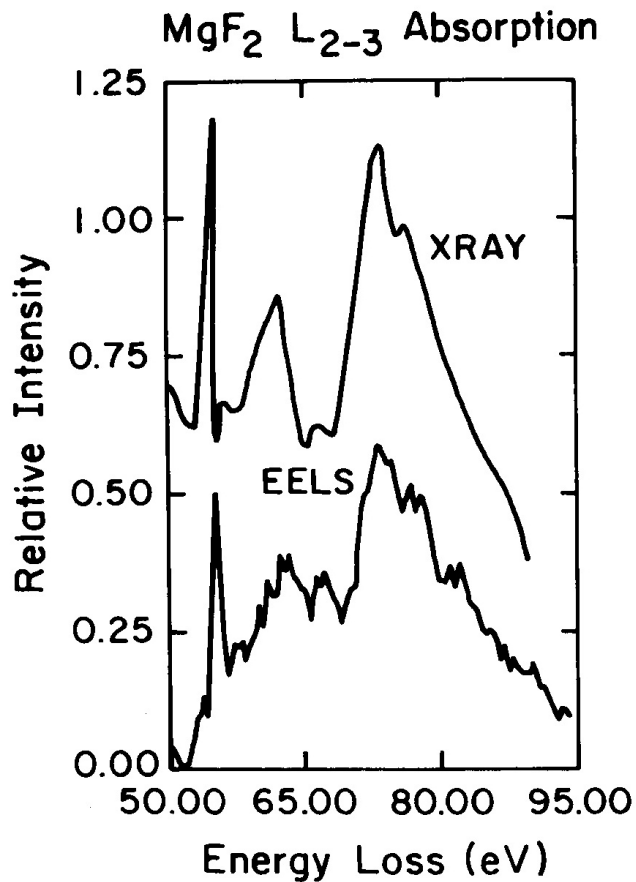
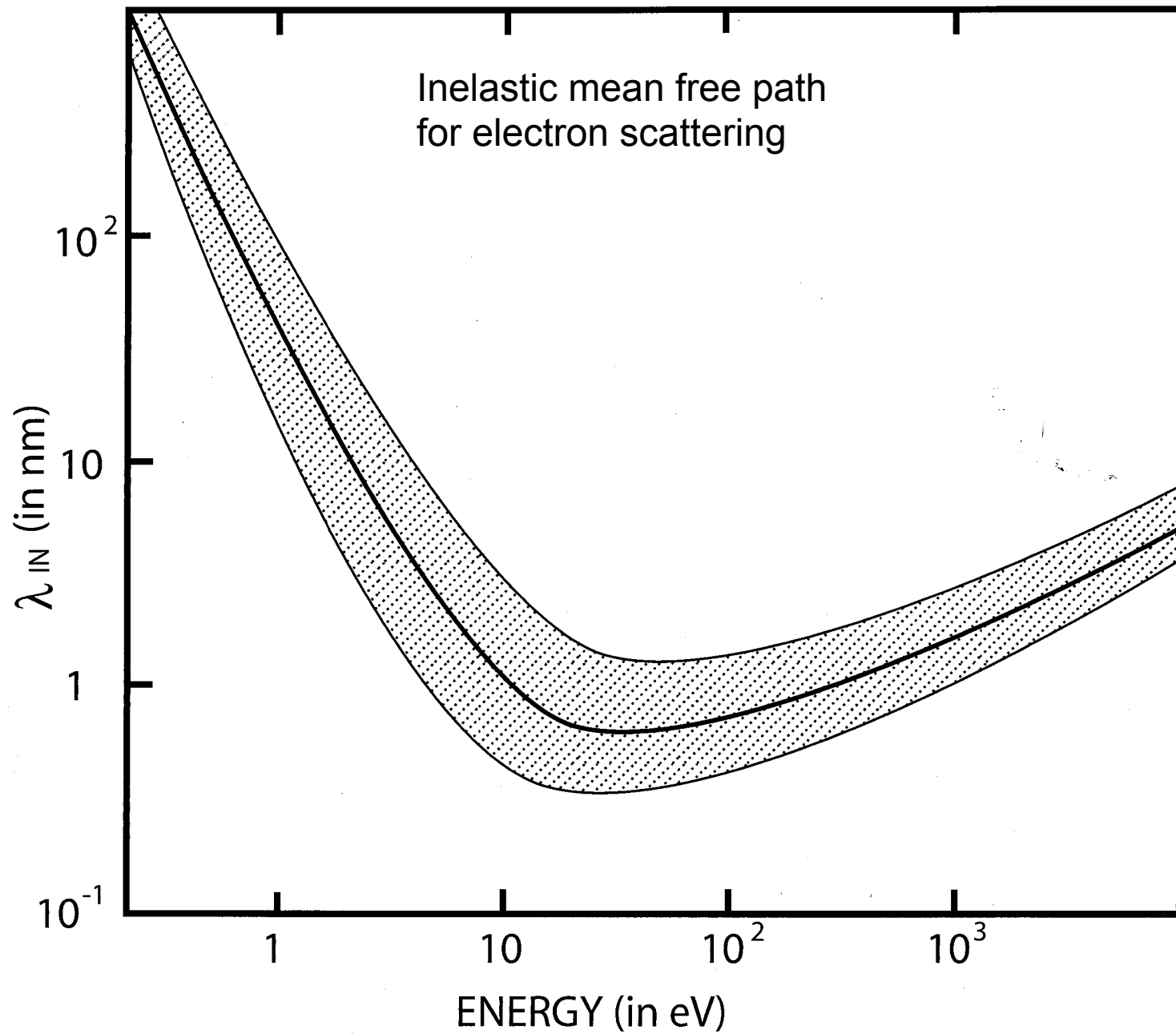


FIG. 3. Relationship between the positions of the peaks in the carbon K -shell fine structure and the theoretical atomic charge as calculated in Refs. (9) and (8). The error bars on the charge indicate the range of the theoretical values.

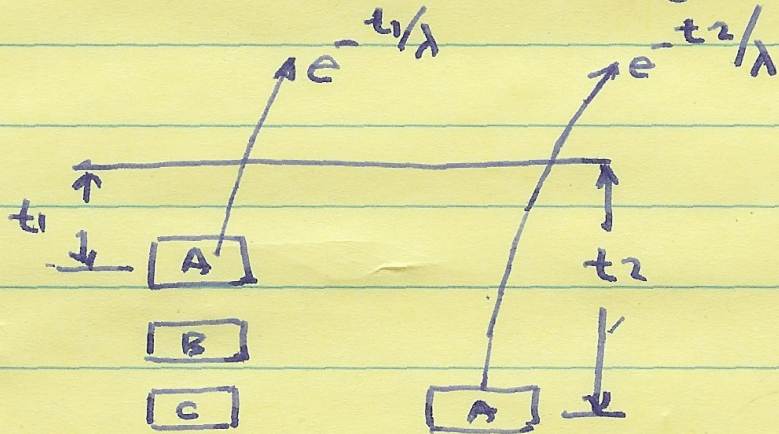
Energy Loss Spectra of Metal Fluorides





From Seah and Dench, 1979. Surf. and Interface Anal.1.36

Effect of Depth on Auger Signal

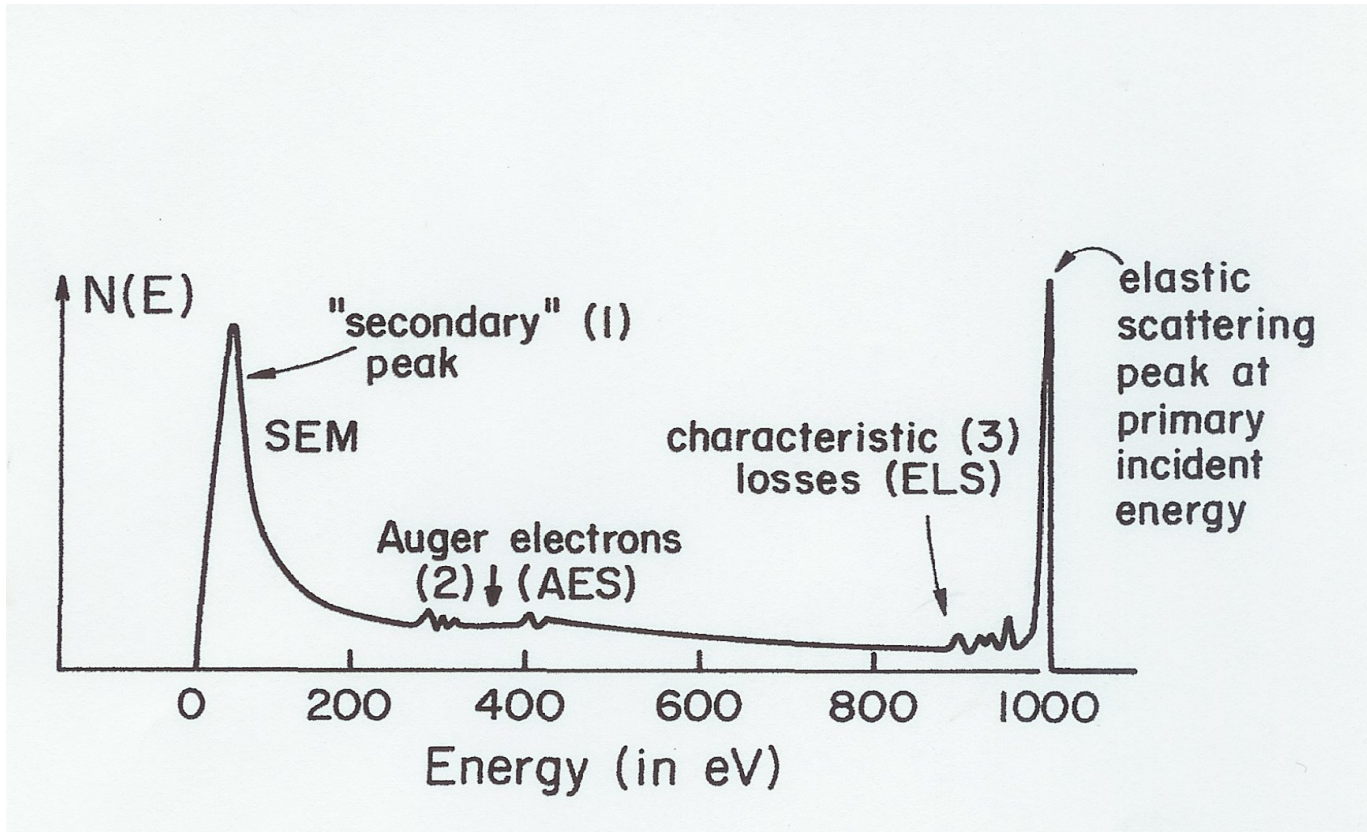


if $\lambda =$ avg. escape depth from matrix, then

$$e^{-t_2/\lambda} < e^{-t_1/\lambda}$$

even if N_A is same in both cases!

Electron Scattering from Solid Sample (“reflection”)



How can we distinguish Auger peaks from ELS peaks?

Electron Scattering

differences in "efficiency factors", F ($S=NJ\delta YF$)

1. EELS (look at primary electron)

$$F_e = \eta_x^e \cdot \eta_{DE}^e \cdot \eta_{DET}^e$$

collection solid angle energy window detector efficiency

2. XRF (look at x-rays emitted)

$$F_x = \eta_{\text{SAMPLE ATTN.}}^x \cdot \eta_x^x \cdot \eta_{DET}^x \cdot \eta_{\text{other}}^x$$

3. Auger (look at emitted Auger electrons)

$$F_A = \eta_x^a \cdot \eta_{BSE}^a \cdot \eta_{\text{SAMPLE}}^a \cdot \eta_{\text{ATTEN}}^a$$